



UNIVERSITY OF ENERGY AND NATURAL RESOURCES, SUNYANI, GHANA

SCHOOL OF ENGINEERING

DEPARTMENT OF COMPUTER AND ELECTRICAL ENGINEERING

Level 300: First Semester Examinations 2018/2019

Bachelor of Science (Computer Engineering, Electrical & Electronic Engineering)

ELNG 303: LINEAR ELECTRONIC CIRCUITS

DECEMBER, 2018

TIME: 2½ hours

INSTRUCTIONS: **ANSWER ALL FIVE QUESTIONS: LECTURE MATERIALS CAN BE USED)**

Question 1 [(2x4)+(2+6)=16]

(a) Briefly explain the following terms as applied to IC fabrication

- (i) Epitaxial Growth
- (ii) Oxidation
- (iii) Photolithography
- (iv) Thin film deposition

(b) A circuit is built around a bi-polar NPN transistor. The base network has a diode and a capacitor in series while the collector is connected to a power supply through a resistor. If the emitter is connected to ground:

- i) Draw the circuit
- ii) Provide all the masking layout of the circuit

Question 2 [(4+(4x2)+(2x2)=14]

(a) Given the circuit of Fig. 2.1, draw the small signal equivalent circuit assuming that $r_D = \infty\Omega$ and show that:

$$V_{o1} = -\frac{g_m R_D}{1+g_m R_s} \quad \text{and} \quad V_{o2} = -\frac{g_m R_s}{1+g_m R_s}$$

For $g_m=2mS$, $R_G=1M\Omega$, $R_s=R_D=5k\Omega$, find V_{o1} and V_{o2} if $V_i=20mV \sin\omega t$.

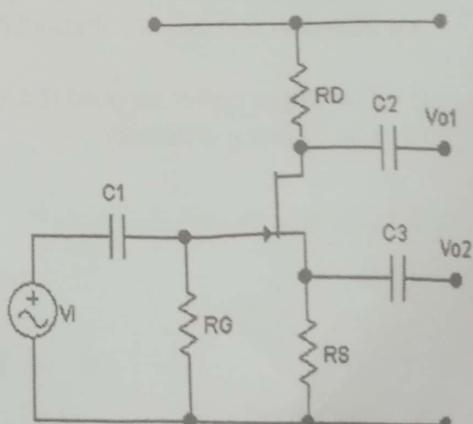


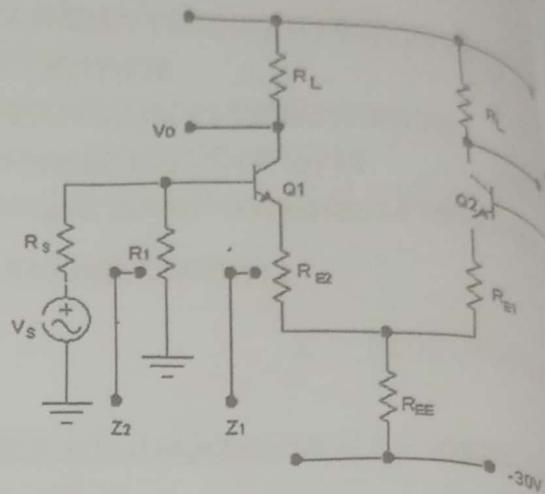
Fig. 2.1

Question 3 [4+(2x5)=14]

(a) State four characteristics of an ideal op-amp.

- (b) For the differential circuit shown in Fig. 3.1, given that $\beta=100$, $R_{E1}=R_{E2}=250\Omega$, $R_{EE}=10k\Omega$, $R_1=50k\Omega$, $R_S=10k\Omega$, $R_L=10k\Omega$ and $V_s = 10mV$, determine:
- The current I_E through R_{EE}
 - The value of r_e , the emitter resistance
 - The impedance Z_1 looking through the base
 - The impedance Z_2
 - The output voltage V_o

Fig. 3.1

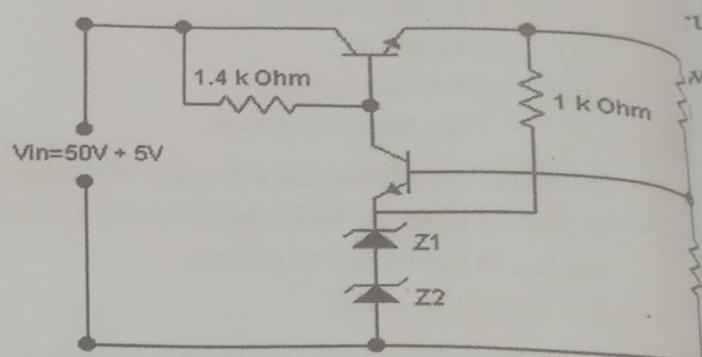


Question 4 [4+4=8]

(a) Distinguish between series and switching voltage regulators

- (b) For the series voltage regulator shown in Fig. 4.1, determine the output regulated voltage if $V_{Z1} = V_{Z2} = 7.5V$, $V_{BE} = 0.7V$, $R_1 = 930\Omega$ and $R_2 = 1570\Omega$.

Fig. 4.1



Question 5 [4+(2x2)=8]

(a) State the differences between the various types of power amplifier

(b) A complementary pair class B push-pull amplifier has a supply voltage of 45 V and the transistors are biased so that they are sinusoidally driven to provide a current 1.2A. Calculate:

- The output power supplied to a speaker having a resistance of 15Ω
- The collector efficiency

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Bachelor of Science (Computer Engineering, Electrical & Electronic Engineering)

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April, 2021

Time: 2½ hours

Material required: Class material (To be brought in by students)

INSTRUCTIONS: ANSWER ALL QUESTIONS (each question carries 15marks)

Question 1

(a) The following processes are used in the fabrication of monolithic ICs, explain each of them in detail:

- i. Oxidation
- ii. Diffusion
- iii. Epitaxy
- iv. Photolithography
- v. Thin Film Deposition

(b) Using the list in (a) provide a step-by-step masking levels of the fabrication of NPN transistor indicating the type of photo-resist used.

Question 2

The two-stage amplifier shown in Fig. 2 is designed with a *FET*, *TR1* and silicon *BJT*, *Q1* with the manufacturer's specifications for β (*Q1*) at 25°C as 150 and g_m (*TR1*) as 3500 μ S.

Given $R_g=1.5k\Omega$, $R_1=6M\Omega$, $R_2=4M\Omega$, $R_d=2.4k\Omega$, $R_s=500\Omega$, $R_3=15k\Omega$, $R_4=4.7k\Omega$, $R_c=2.7k\Omega$, $R_e=470\Omega$, $R_L=2.2k\Omega$ and supply voltage as 20V. Using the Fig. 2 and component values given, answer the following questions.

Calculate:

- i) Emitter current I_E
- ii) Emitter resistance r_e
- iii) Voltage gain at stage 2, A_{v2}
- iv) Calculate input impedance of the second stage, Z_2
- v) Calculate the gain of the first stage, A_{v1}
- vi) Calculate the input impedance of the first stage Z_1
- vii) Calculate the overall gain, A
- viii) If v_g is a sinusoidal voltage of 5mV $\cos\omega t$, what will the output voltage be?

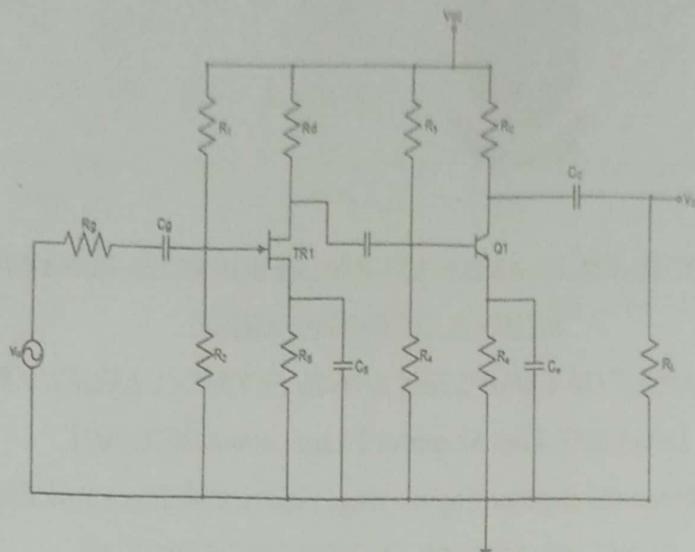


Fig. 2

Question 3

- State and explain the different types of power amplifiers
- A complementary pair class B push-pull amplifier has a supply voltage of 45 V and the transistors are biased so that they are sinusoidally driven to provide a current which is 0.75 of the maximum value. Calculate:
 - The output power supplied to a speaker having a resistance of 15Ω
 - The collector efficiency
 - The power dissipation of the transistors.

Question 4

- State the characteristics of an ideal op-amp.
- Fig. 4 shows the schematic of the two op-amp instrumentation amplifier. Find
 - An expression for V_{O1} and V_{O2}
 - Hence or otherwise an expression if $R_1 = R_2 = R_3 = R$
 - The current through R_L if $R_L = 10K\Omega$ and $V_i = 5V$

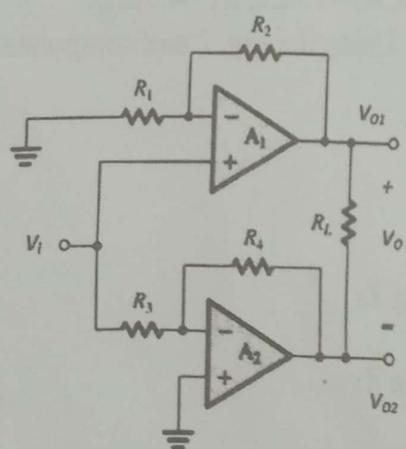


Fig. 4